

Supplementary Information

Quasi-3D Sb₂S₃/Reduced Graphene Oxide/MXene (Ti₃C₂T_x) Hybrid for High-rate and Durable Sodium-Ion Batteries

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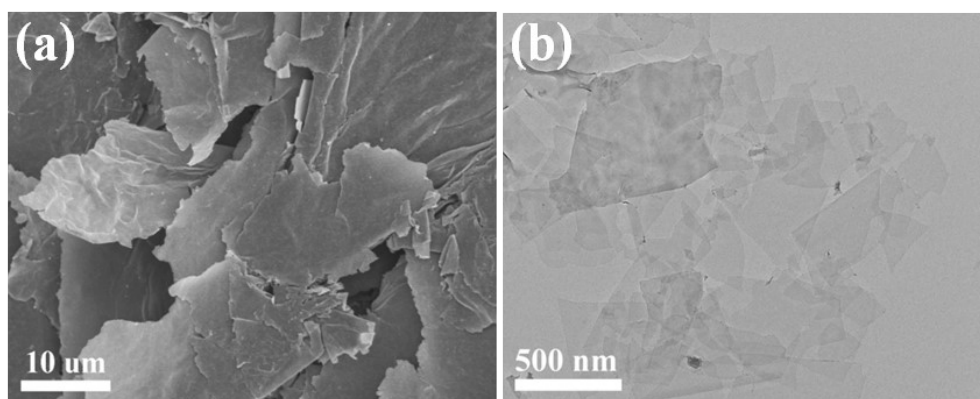


Fig. S1 (a) SEM and (b) TEM images of the $\text{Ti}_3\text{C}_2\text{T}_x$ MXene.

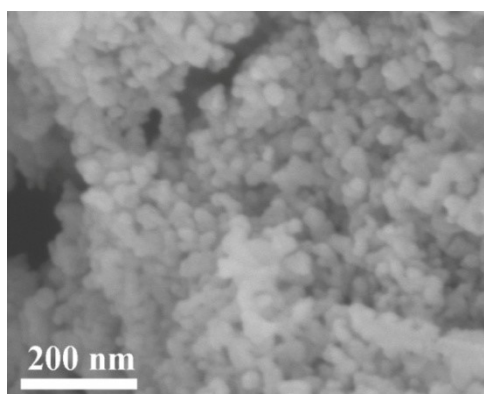


Fig. S2 SEM image of the Sb_2S_3 nanoparticles.

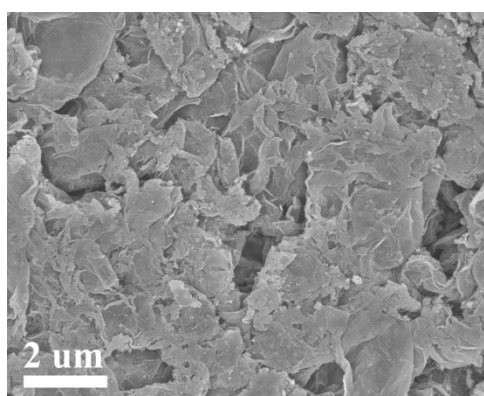


Fig. S3 SEM image of the $\text{Sb}_2\text{S}_3/\text{RGO}/\text{MXene}$ composite.

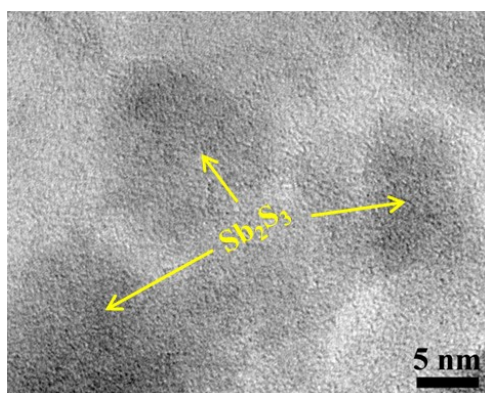


Fig. S4 HRTEM image of the $\text{Sb}_2\text{S}_3/\text{RGO}/\text{MXene}$ composite.

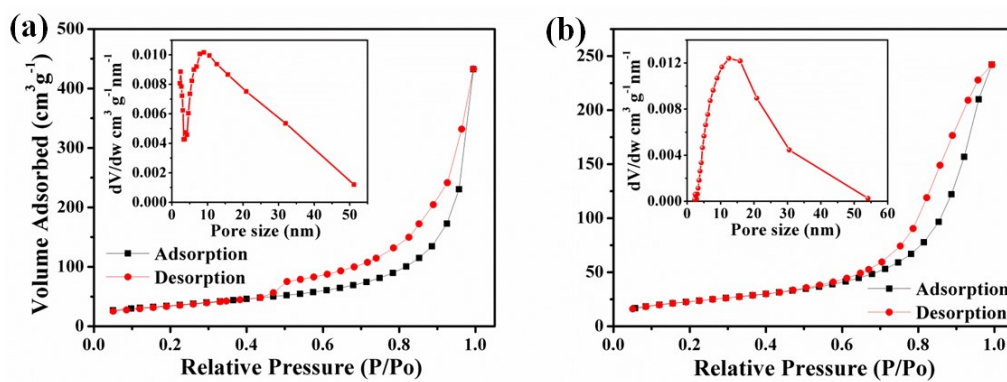


Fig. S5 N_2 adsorption/desorption isotherms and the corresponding pore size distribution curve (inset) of the (a) $\text{Sb}_2\text{S}_3/\text{RGO}$ and (b) $\text{Sb}_2\text{S}_3/\text{MXene}$ composite.

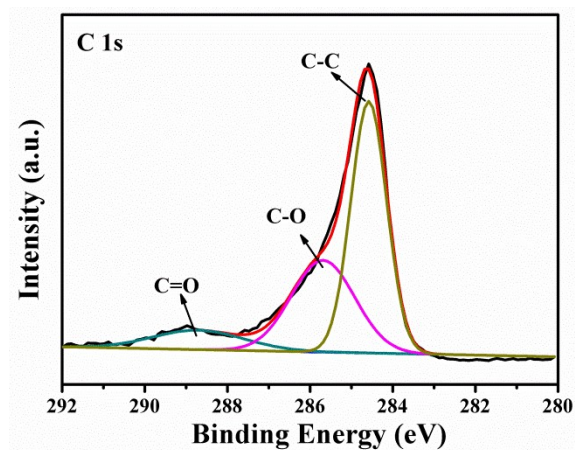


Fig. S6 the high-resolution C 1s XPS spectra of Sb₂S₃/RGO composite

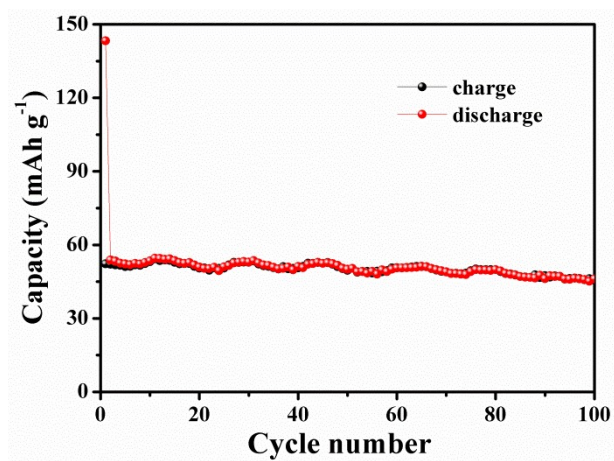


Fig. S7 Cycling performances of the 3D RGO/MXene electrode

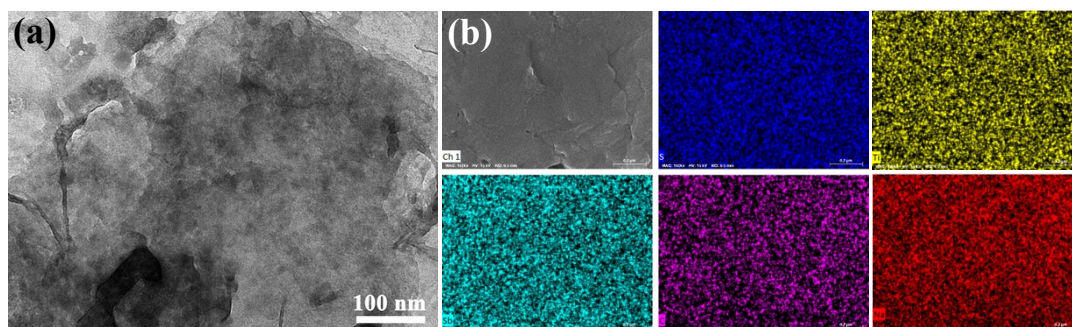


Fig. S8 (a) TEM image of $\text{Sb}_2\text{S}_3/\text{RGO}/\text{MXene}$ after 50 cycles at $0.2 \text{ A} \cdot \text{g}^{-1}$. (b) TEM elemental-mapping images for C, S, Sb, Ti and Na.

Table S1 Electrochemical performance comparison between the $\text{Sb}_2\text{S}_3/\text{RGO}/\text{MXene}$ composite and previously reported Sb_2S_3 -based composites.

| Materials | Cycling stability (mAh g^{-1}) | Rate capability (mAh g^{-1}) |
|---|--|--|
| $\text{Sb}_2\text{S}_3/\text{CS}^1$ | 321 after 200 cycles at $0.2 \text{ A} \cdot \text{g}^{-1}$ | 221 at $5 \text{ A} \cdot \text{g}^{-1}$ |
| $\text{Sb}_2\text{S}_3@\text{MWCNTs}^2$ | 412.3 after 50 cycles at $0.05 \text{ A} \cdot \text{g}^{-1}$ | 399.1 at $1 \text{ A} \cdot \text{g}^{-1}$ |
| Sb_2S_3 nanorods@ C^3 | 570 after 100 cycles at $0.1 \text{ A} \cdot \text{g}^{-1}$ | 337 at $2 \text{ A} \cdot \text{g}^{-1}$ |
| Sb_2S_3 hollow microspheres ⁴ | 384 after 50 cycles at $0.2 \text{ A} \cdot \text{g}^{-1}$ | 275 at $4 \text{ A} \cdot \text{g}^{-1}$ |
| $\text{Sb}_2\text{S}_3/\text{PPy}$ Microspheres ⁵ | 427 after 50 cycles at $0.1 \text{ A} \cdot \text{g}^{-1}$ | 513 at $1 \text{ A} \cdot \text{g}^{-1}$ |
| amorphous Sb_2S_3 anoparticle ⁶ | 586 after 100 cycles at $0.05 \text{ A} \cdot \text{g}^{-1}$ | 534 at $3 \text{ A} \cdot \text{g}^{-1}$ |
| $\text{Sn}@\text{Sb}_2\text{S}_3\text{-rGO}^7$ | 541 after 70 cycles at $0.5 \text{ A} \cdot \text{g}^{-1}$ | 360 at $5 \text{ A} \cdot \text{g}^{-1}$ |
| $\text{Sb}_2\text{S}_3/\text{C}^8$ | 538 after 100 cycles at $0.2 \text{ A} \cdot \text{g}^{-1}$ | 520 at $2 \text{ A} \cdot \text{g}^{-1}$ |
| $\text{MWNTs}@\text{Sb}_2\text{S}_3@\text{PPy}^9$ | 500 after 85 cycles at $0.1 \text{ A} \cdot \text{g}^{-1}$ | 376 at $2 \text{ A} \cdot \text{g}^{-1}$ |
| This work | 633.3 after 100 cycles at $0.2 \text{ A} \cdot \text{g}^{-1}$ 442.6 after 500 cycles at $2 \text{ A} \cdot \text{g}^{-1}$ | 510.1 at $4 \text{ A} \cdot \text{g}^{-1}$ |

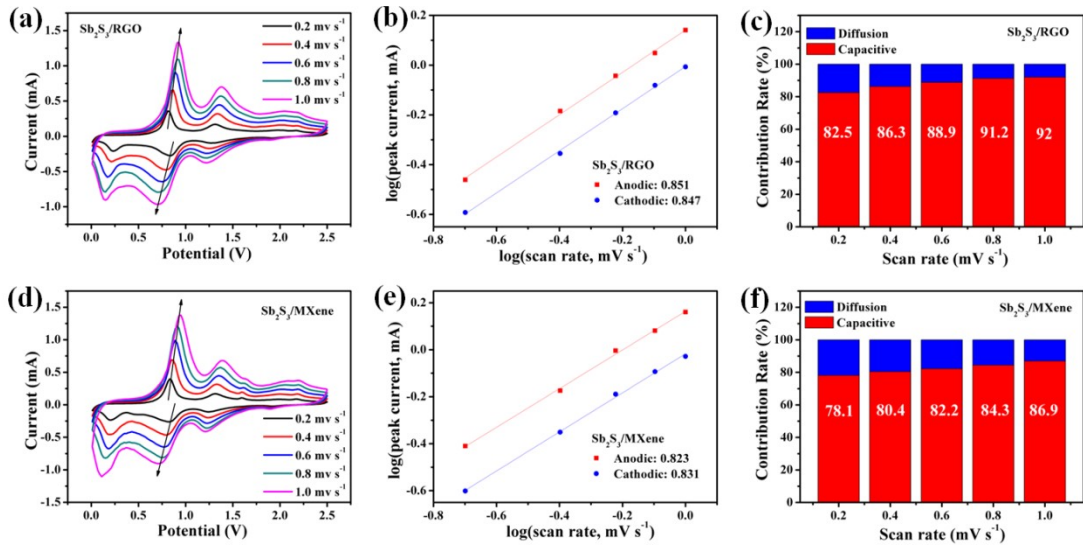


Fig. S9 (a, d) CV curves of the Sb₂S₃/RGO and Sb₂S₃/MXene electrode at different scan rates. (b, e) Corresponding log(i) versus log(v) plots for different redox peaks, respectively. (c, f) Capacitive contributions of the Sb₂S₃/RGO and Sb₂S₃/MXene electrode at various scan rates.

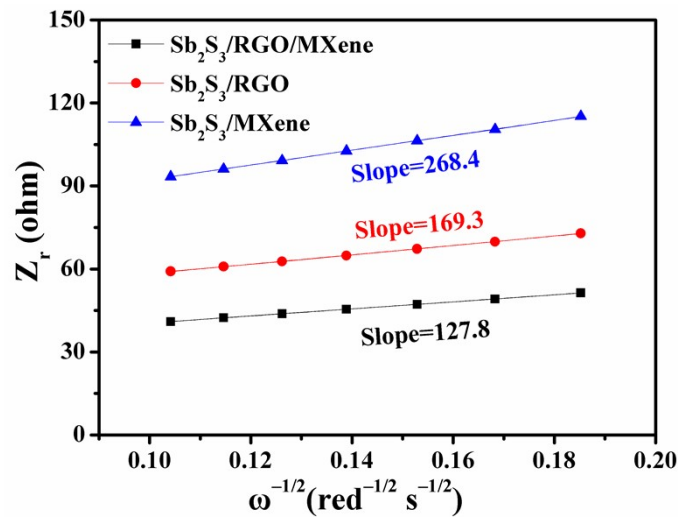


Fig. S10 Linear fits (relationship between Z' and $\omega^{-1/2}$) in low-frequency region of the Sb₂S₃/RGO, Sb₂S₃/MXene and Sb₂S₃/RGO/MXene.

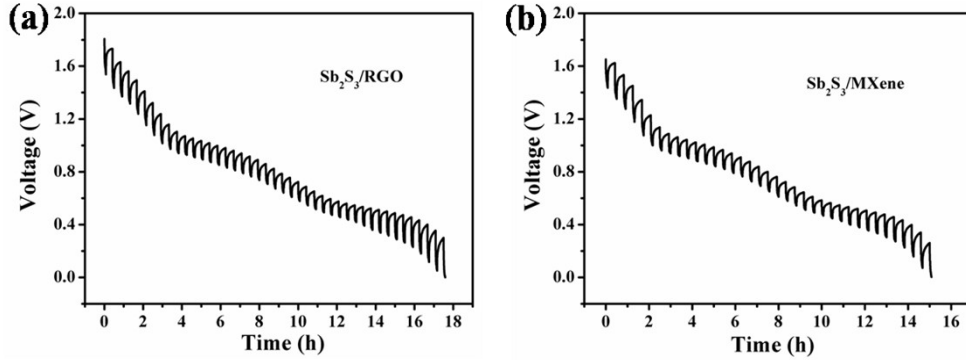


Fig. 11 The GITT curves of the $\text{Sb}_2\text{S}_3/\text{RGO}$ and $\text{Sb}_2\text{S}_3/\text{MXene}$ electrodes.

The value of D_{GITT} can be calculated by applying the following equation:

$$D_{\text{GITT}} = \frac{4}{\pi\tau} \left(\frac{nVm}{A} \right)^2 \left(\frac{\Delta E_s}{\Delta E_\tau} \right)^2 \left(\tau \ll \frac{L^2}{D} \right) \quad (\text{S1})$$

In equation S1, τ represents the pulse time; n is the amount of substance of the material, Vm is the molar volume of the material; A is the area of the electrode; L is the thickness of the electrode; ΔE_s is the voltage change caused by the pulse; ΔE_τ represents the voltage change during the pulse.

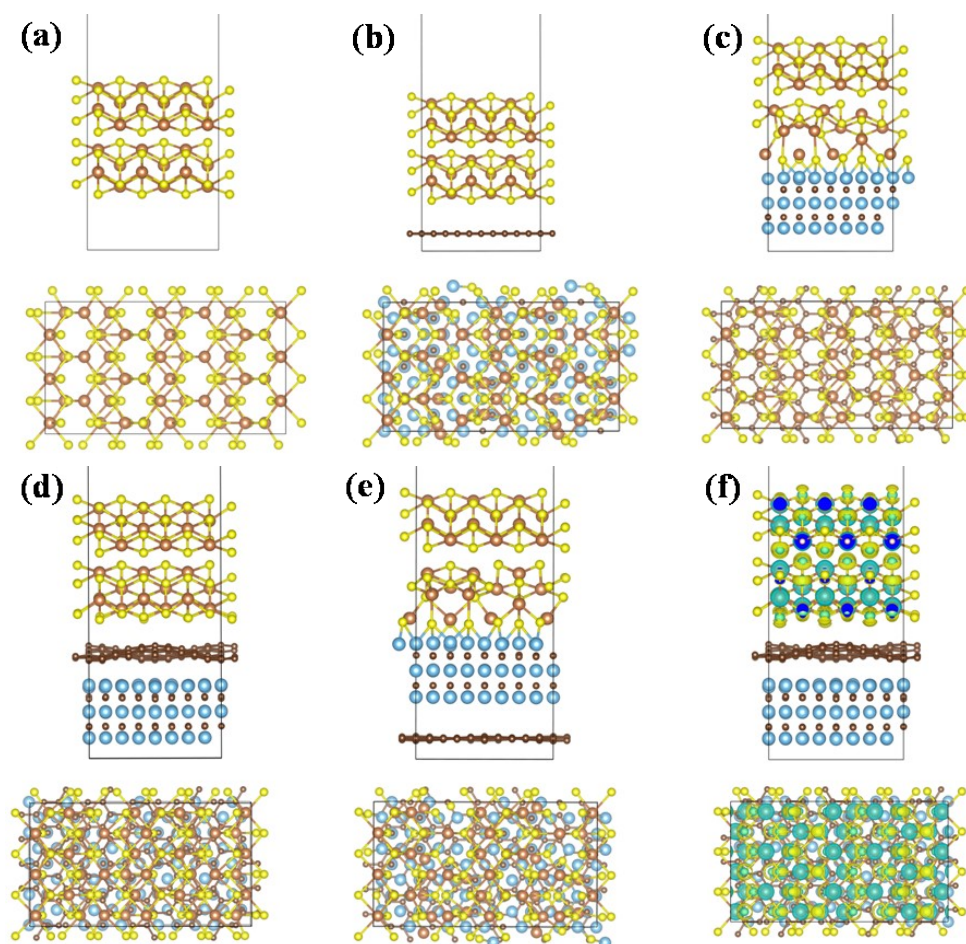


Fig. S12 Optimized structures for the adsorption of Na^+ on (a) Sb_2S_3 , (b) $\text{Sb}_2\text{S}_3/\text{RGO}$, (c) $\text{Sb}_2\text{S}_3/\text{MXene}$, (d) $\text{Sb}_2\text{S}_3\text{-RGO-MXene}$ and (e) $\text{Sb}_2\text{S}_3\text{-MXene-RGO}$ at side (top) and top (bottom) views. (f) Differential charge density of the $\text{Sb}_2\text{S}_3\text{-RGO-MXene}$ at side (top) and top (bottom) views.

Table S2 The adsorption energy of Na^+ on the Sb_2S_3 , $\text{Sb}_2\text{S}_3/\text{RGO}$, $\text{Sb}_2\text{S}_3/\text{MXene}$ and $\text{Sb}_2\text{S}_3/\text{RGO}/\text{MXene}$.

| | Sb_2S_3 | $\text{Sb}_2\text{S}_3/\text{RGO}$ | $\text{Sb}_2\text{S}_3/\text{MXene}$ | $\text{Sb}_2\text{S}_3/\text{RGO}/\text{MXene}$ | |
|------------------|-------------------------|------------------------------------|--------------------------------------|---|--|
| | | | | $\text{Sb}_2\text{S}_3\text{-RGO-MXene}$ | $\text{Sb}_2\text{S}_3\text{-MXene-RGO}$ |
| E_{ads} | 1.38 eV | 1.36 eV | 1.40 eV | 1.35 eV | 1.49 eV |

References

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